Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** 0.104 inches **Terminal Length:** 0.062 inches **Overall Height:** 0.043 inches **Overall Width:** 0.104 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 reverse voltage, dc Voltage Tolerance In Percent: -10.0/+10.0 **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: Demilitarization: No Fiig: A110a0